

SN74LVC3GU04

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#### SCES539D - JANUARY 2004 - REVISED DECEMBER 2013

# **Triple Inverter Gate**

Check for Samples: SN74LVC3GU04

## **FEATURES**

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V •
- Max t<sub>pd</sub> of 3.9 ns at 3.3 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- ±24-mA Output Drive at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- **loff Support Live Insertion, Partial Power Down** Mode and Back Drive Protection
- **Unbuffered Outputs**

1A [

3Y [

GND [

2A 🗌

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22** 
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

2

3

4

1000-V Charged-Device Model (C101)

DCT PACKAGE (TOP VIEW)

8

7

6

5

2Y

# DESCRIPTION

This triple inverter is designed for 1.65-V to 5.5-V  $V_{CC}$ operation.

The SN74LVC3GU04 contains three inverters with unbuffered outputs and performs the Boolean function  $Y = \overline{A}$ .

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

	DCU PACKAGE (TOP VIEW)												
	1A 🖂 1	8 V <sub>cc</sub>											
L CC	3Y 🔲 2	7 🖽 1Y											
1Y	2A 🔲 3	6 🗔 3A											
3A	GND 🎞 4	5 🛄 2Y											

YZP	PAC	KAGE
(BOT	том	VIEW)

GND		
2A	O36O	3A
3Y	0270	1Y
1A	0180	$V_{CC}$

See mechanical drawings for dimensions.



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# SN74LVC3GU04



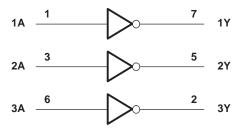
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Function Table (Each Inverter)									
INPUT A	OUTPUT Y								
Н	L								
L	Н								

### Logic Diagram (Positive Logic)



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			I	MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-	-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>		-	-0.5	6.5	V
Vo	Output voltage range <sup>(2)</sup> (3)		-	-0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0			-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0			-50	mA
I <sub>O</sub>	Continuous output current				±50	mA
	Continuous current through $V_{\mbox{\scriptsize CC}}$ or GND				±100	mA
		DCT package			220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package			227	°C/W
		YZP package			102	
T <sub>stg</sub>	Storage temperature range			-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.



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## **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.65	5.5	V
VIH	High-level input voltage	I <sub>O</sub> = −100 μA	0.75 × V <sub>CC</sub>		V
VIL	Low-level input voltage	I <sub>O</sub> = 100 μA		$0.25 \times V_{CC}$	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
		V <sub>CC</sub> = 2.3 V		-8	
I <sub>OH</sub>	High-level output current	N		-16	mA
		V <sub>CC</sub> = 3 V		-24	
		V <sub>CC</sub> = 4.5 V		-32	
		V <sub>CC</sub> = 1.65 V		4	
		$V_{CC} = 2.3 V$		8	
I <sub>OL</sub>	L Low-level output current	N 2.11		16	mA
		V <sub>CC</sub> = 3 V			
	Low-level input voltage Input voltage Output voltage High-level output current	$V_{CC} = 4.5 V$		32	
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETE		TEAT CONDITIONS		-40°	C to 85°C		–40°C to 125°C				
R		TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	MIN	TYP <sup>(1)</sup>	MAX	UN	
		I <sub>OH</sub> = -100 mA	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1			V <sub>CC</sub> - 0.1				
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			1.2				
V <sub>OH</sub>	V <sub>IL</sub> = 0 V	I <sub>OH</sub> = -8 mA	2.3 V	1.9			1.9			\	
		$I_{OH} = -16 \text{ mA}$	3 V	2.4			2.4				
	$I_{OH} = -24 \text{ mA}$ $I_{OH} = -32 \text{ mA}$	I <sub>OH</sub> = -24 mA	3 V	2.3			2.3				
		I <sub>OH</sub> = -32 mA	4.5 V	3.8			3.8				
	I <sub>OL</sub> =	I <sub>OL</sub> = 100 mA	1.65 V to 5.5 V			0.1			0.1		
		I <sub>OL</sub> = 4 mA	1.65 V			0.45			0.45		
V <sub>OL</sub>	$V_{IH} = V_{CC}$	I <sub>OL</sub> = 8 mA	2.3 V			0.3			0.3	,	
		I <sub>OL</sub> = 16 mA	3 V			0.4			0.4		
		$I_{OL} = 24 \text{ mA}$	3 V			0.55			0.75		
		I <sub>OL</sub> = 32 mA	4.5 V			0.55			0.75		
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or	r GND	0 to 5.5 V			±5			±5	۲	
I <sub>CC</sub>	V <sub>I</sub> = 5.5 V or	r GND, I <sub>O</sub> = 0	1.65 V to 5.5 V			10			10	μ	
Ci	$V_{I} = V_{CC}$ or $Q$	GND	3.3 V		7					p	

(1) All typical values are at  $V_{CC} = 3.3$  V,  $T_A = 25^{\circ}C$ .

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### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER FROM (INPUT)		SN74LVC3GU04 -40°C to 85°C									
		TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y	0.2	9.2	0.2	4	0.6	3.9	0.5	3.2	ns

## **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER FROM (INPUT)			SN74LVC3GU04 –40°C to 125°C								
		TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y	0.2	10.5	0.2	4.5	0.6	4.7	1.1	4	ns

## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT	
	FARAMETER	TEST CONDITIONS	ТҮР	ТҮР	TYP	TYP	UNIT	
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	8	8	11	23	pF	

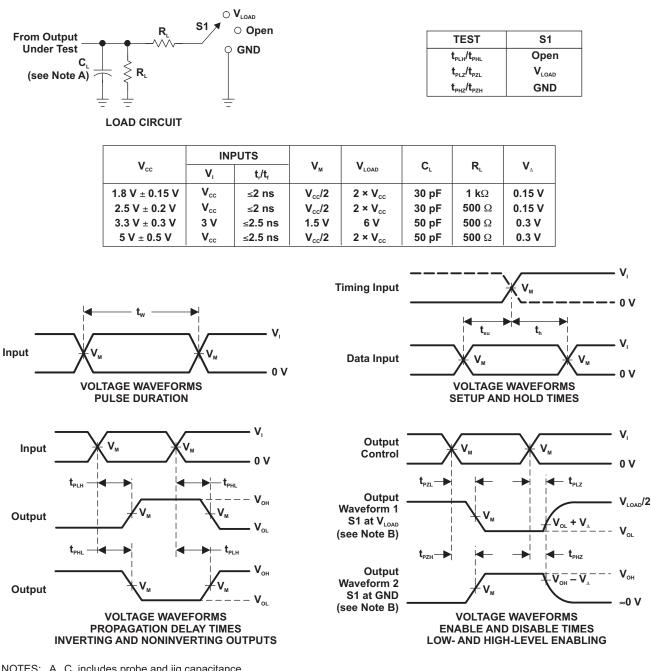


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### Parameter Measurement Information



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{\mbox{\tiny PLH}}$  and  $t_{\mbox{\tiny PHL}}$  are the same as  $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

### Figure 1. Load Circuit and Voltage Waveforms

# **REVISION HISTORY**

### Changes from Revision C (Feburary 2007) to Revision D Page Removed Ordering Information table. 2 Updated operating temperature range. ..... 3

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17-Aug-2015

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
74LVC3GU04DCURE4	ACTIVE	VSSOP	DCU	8		TBD	Call TI	Call TI	-40 to 125		Samples
SN74LVC3GU04DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	CU4 Z	Samples
SN74LVC3GU04DCUR	ACTIVE	VSSOP	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 125	(CU4Q ~ CU4R)	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC3GU04DCTR	SM8	DCT	8	3000	180.0	13.0	3.35	4.5	1.55	4.0	12.0	Q3
SN74LVC3GU04DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3

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# PACKAGE MATERIALS INFORMATION

1-Apr-2017



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC3GU04DCTR	SM8	DCT	8	3000	182.0	182.0	20.0
SN74LVC3GU04DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.





- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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